

Thyristors

BT145 series

GENERAL DESCRIPTION

Glass passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

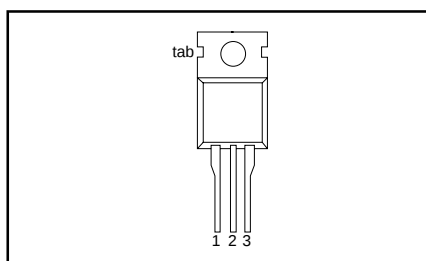
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{DRM} , V_{RRM}	BT145- Repetitive peak off-state voltages	500R 500	600R 600	800R 800	V
$I_{T(AV)}$	Average on-state current	16	16	16	A
$I_{T(RMS)}$	RMS on-state current	25	25	25	A
I_{TSM}	Non-repetitive peak on-state current	300	300	300	A

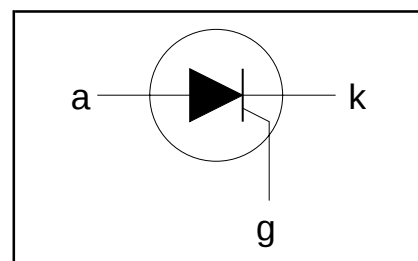
PINNING - TO220AB

PIN	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{DRM} , V_{RRM}	Repetitive peak off-state voltages		-	-500R 500 ¹	-600R 600 ¹	-800R 800	V
$I_{T(AV)}$	Average on-state current	half sine wave; $T_{mb} \leq 101^\circ\text{C}$	-	16			A
$I_{T(RMS)}$	RMS on-state current	all conduction angles	-	25			A
I_{TSM}	Non-repetitive peak on-state current	half sine wave; $T_j = 25^\circ\text{C}$ prior to surge	-	300			A
		$t = 10\text{ ms}$	-	330			A
		$t = 8.3\text{ ms}$	-	450			A ² s
		$t = 10\text{ ms}$	-	200			A/μs
I_{GM}	Peak gate current	$I_{TM} = 50\text{ A}$; $I_G = 0.2\text{ A}$; $dI_G/dt = 0.2\text{ A}/\mu\text{s}$	-	5			A
V_{GM}	Peak gate voltage		-	5			V
V_{RGM}	Peak reverse gate voltage		-	5			V
P_{GM}	Peak gate power		-	20			W
$P_{G(AV)}$	Average gate power	over any 20 ms period	-	0.5			W
T_{stg}	Storage temperature		-40	150			°C
T_j	Operating junction temperature		-	125			°C

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/μs.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air	-	-	1.0	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{GT}	Gate trigger current	$V_D = 12\ \text{V}$; $I_T = 0.1\ \text{A}$	-	5	35	mA
I_L	Latching current	$V_D = 12\ \text{V}$; $I_{GT} = 0.1\ \text{A}$	-	25	80	mA
I_H	Holding current	$V_D = 12\ \text{V}$; $I_{GT} = 0.1\ \text{A}$	-	20	60	mA
V_T	On-state voltage	$I_T = 30\ \text{A}$	-	1.1	1.5	V
V_{GT}	Gate trigger voltage	$V_D = 12\ \text{V}$; $I_T = 0.1\ \text{A}$	-	0.6	1.0	V
I_D, I_R	Off-state leakage current	$V_D = V_{DRM(max)}$; $I_T = 0.1\ \text{A}$; $T_j = 125\ ^\circ\text{C}$	0.25	0.4	-	V
		$V_D = V_{DRM(max)}$; $V_R = V_{RRM(max)}$; $T_j = 125\ ^\circ\text{C}$	-	0.2	1.0	mA

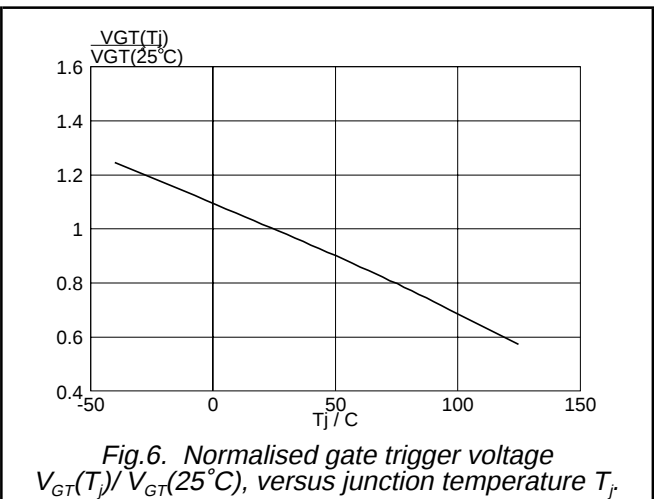
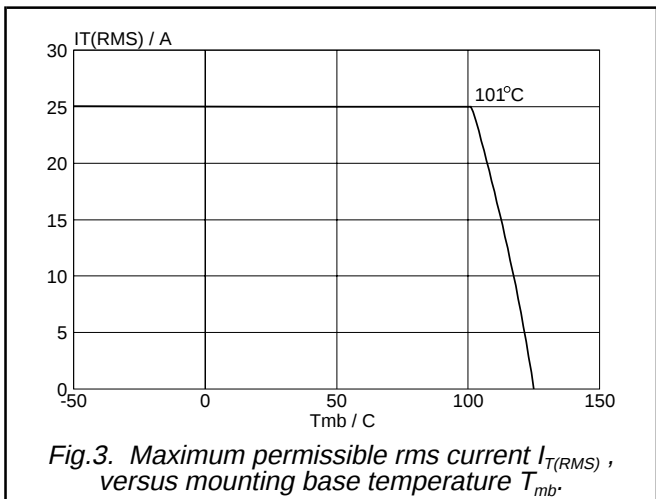
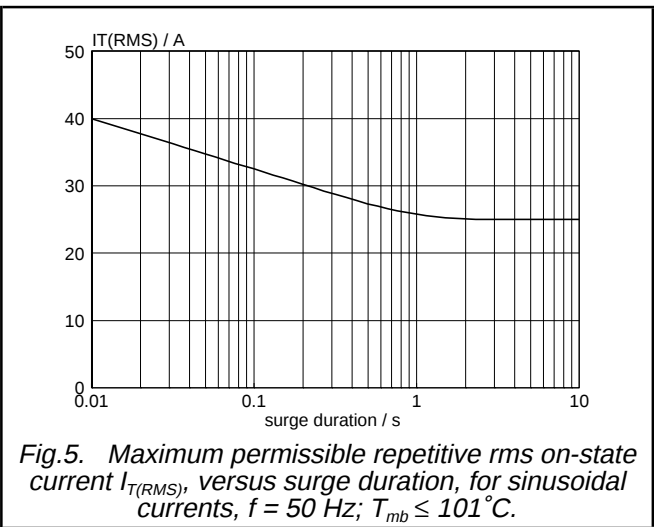
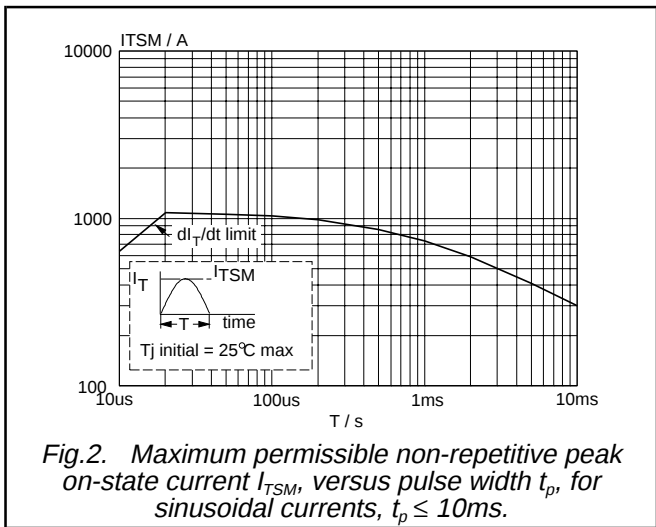
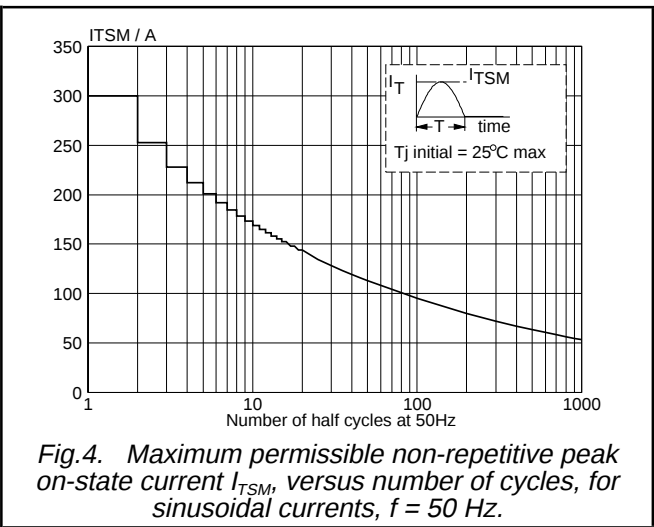
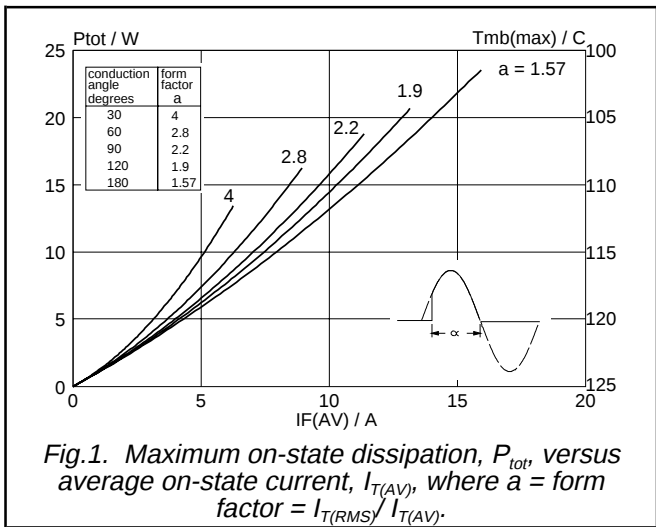
DYNAMIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV_D/dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\ ^\circ\text{C}$; exponential waveform; gate open circuit	200	500	-	V/ μs
t_{gt}	Gate controlled turn-on time	$I_{TM} = 40\ \text{A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\ \text{A}$; $dI_G/dt = 5\ \text{A}/\mu\text{s}$	-	2	-	μs
t_q	Circuit commutated turn-off time	$V_D = 67\% V_{DRM(max)}$; $T_j = 125\ ^\circ\text{C}$; $I_{TM} = 50\ \text{A}$; $V_R = 25\ \text{V}$; $dI_{TM}/dt = 30\ \text{A}/\mu\text{s}$; $dV_D/dt = 50\ \text{V}/\mu\text{s}$	-	70	-	μs

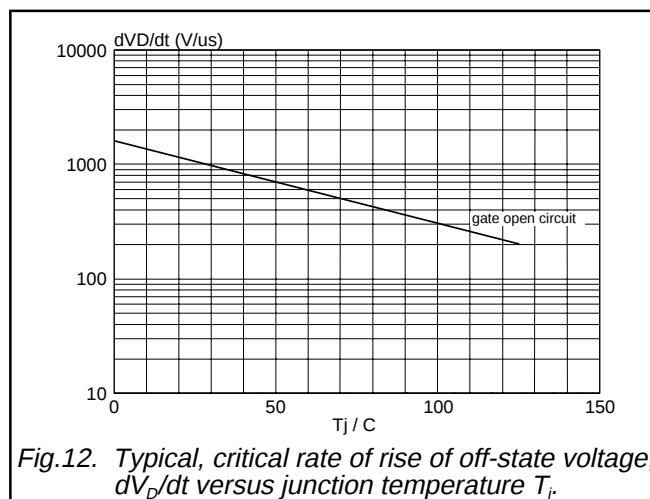
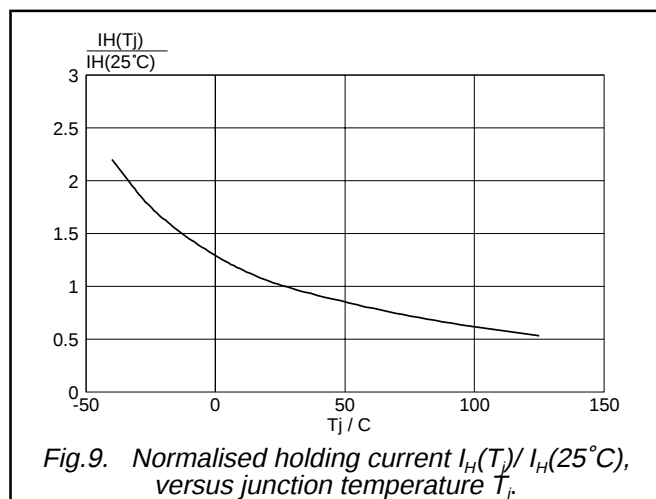
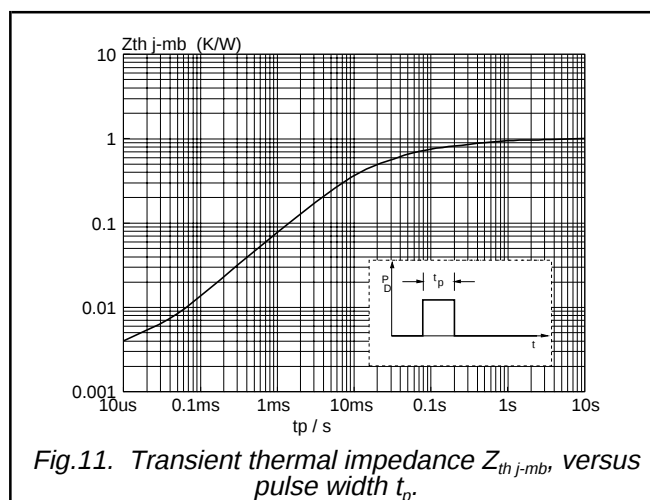
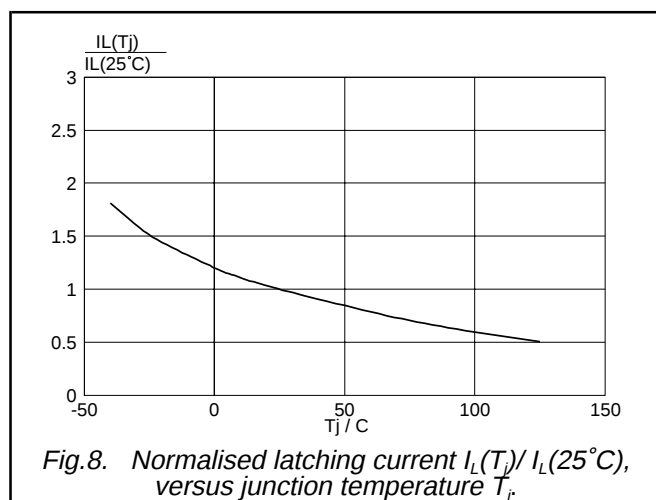
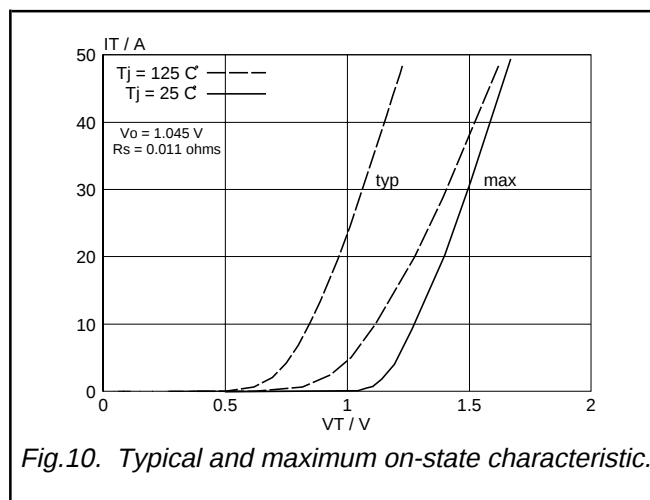
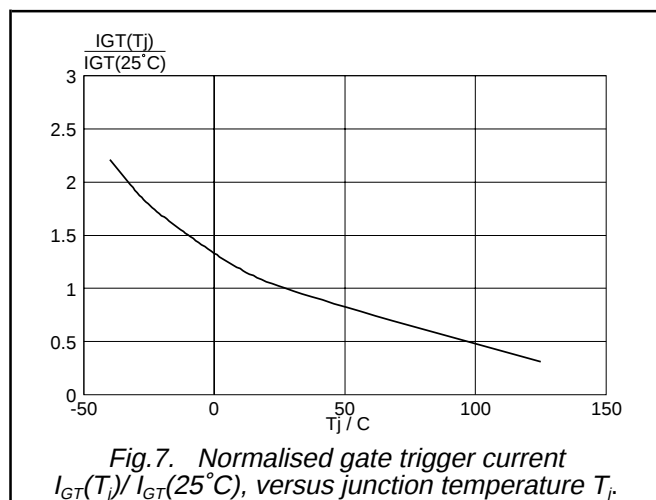
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MECHANICAL DATA

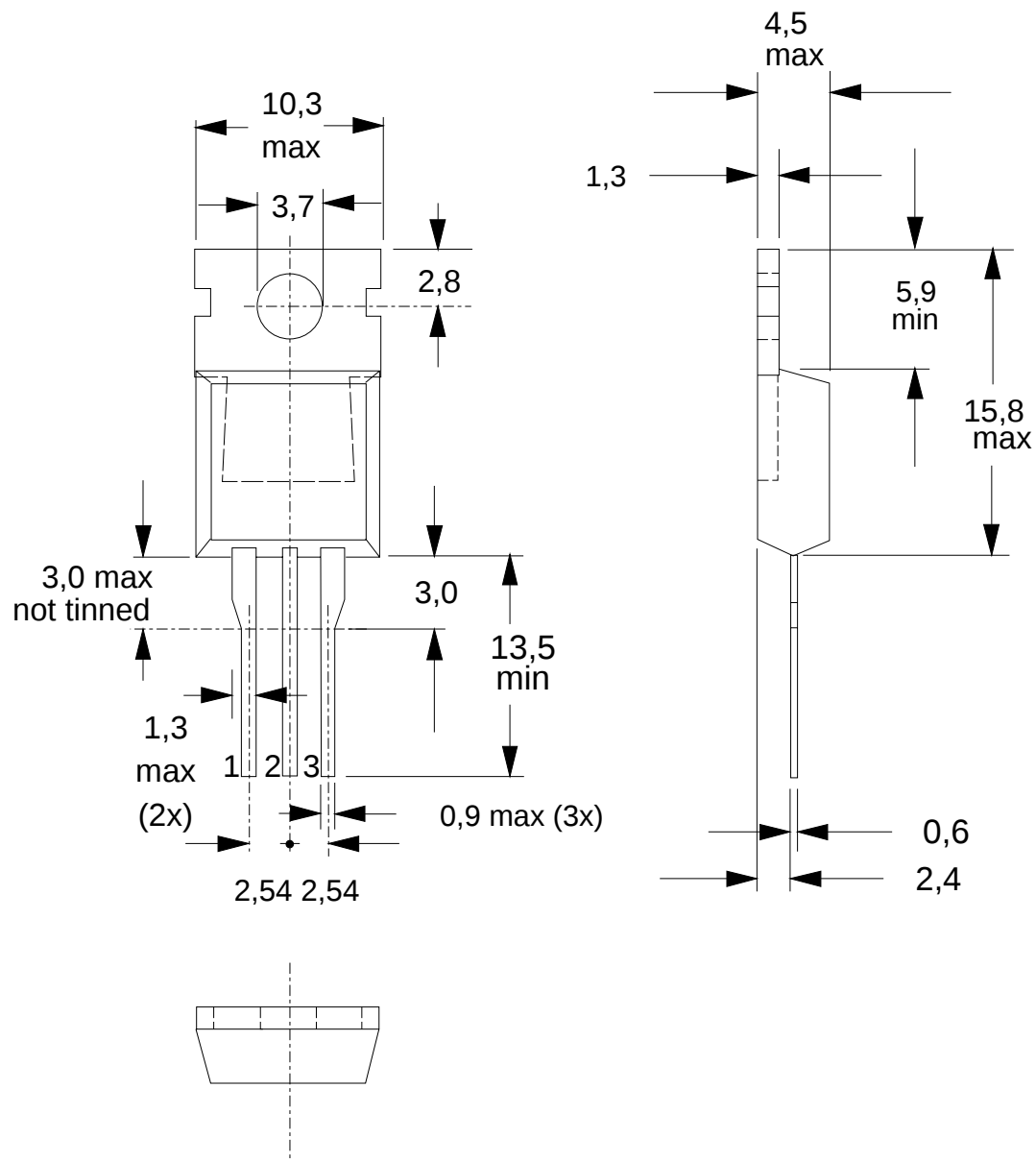
*Dimensions in mm**Net Mass: 2 g*

Fig.13. TO220AB; pin 2 connected to mounting base.

Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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